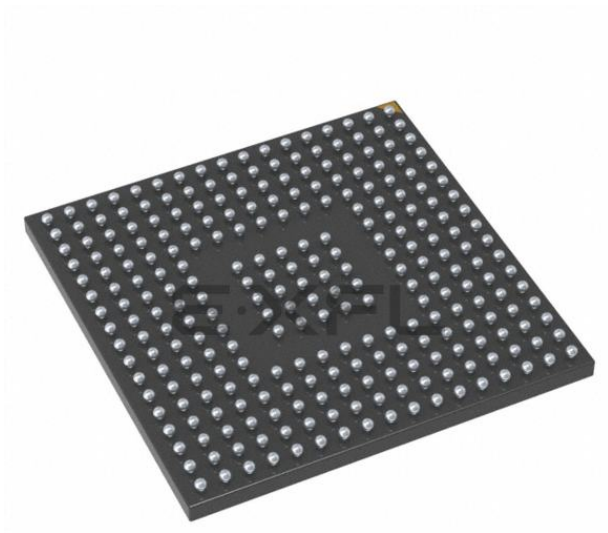




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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I ² C, IrDA, LINbus, SAI, SDIO, SPI, UART/USART, USB, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I ² S, LCD, POR, PWM, WDT
Number of I/O	114
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	384K x 8
Voltage - Supply (Vcc/Vdd)	1.7V ~ 3.6V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	201-UFBGA
Supplier Device Package	176+25UFBGA (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f469igh6

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1 Description

The STM32F469xx devices are based on the high-performance ARM® Cortex®-M4 32-bit RISC core operating at a frequency of up to 180 MHz. The Cortex®-M4 core features a Floating point unit (FPU) single precision which supports all ARM® single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security.

The STM32F469xx devices incorporate high-speed embedded memories (Flash memory up to 2 Mbytes, up to 384 Kbytes of SRAM), up to 4 Kbytes of backup SRAM, and an extensive range of enhanced I/Os and peripherals connected to two APB buses, two AHB buses and a 32-bit multi-AHB bus matrix.

All devices offer three 12-bit ADCs, two DACs, a low-power RTC, twelve general-purpose 16-bit timers including two PWM timers for motor control, two general-purpose 32-bit timers, and a true random number generator (RNG). They also feature standard and advanced communication interfaces:

- Up to three I²Cs
- Six SPIs, two I²Ss full duplex. To achieve audio class accuracy, the I²S peripherals can be clocked via a dedicated internal audio PLL or via an external clock to allow synchronization.
- Four USARTs plus four UARTs
- An USB OTG full-speed and a USB OTG high-speed with full-speed capability (with the ULPI),
- Two CANs
- One SAI serial audio interface
- An SDMMC host interface
- Ethernet and camera interface
- LCD-TFT display controller
- Chrom-ART Accelerator™
- DSI Host.

Advanced peripherals include an SDMMC interface, a flexible memory control (FMC) interface, a Quad-SPI Flash memory, and camera interface for CMOS sensors. Refer to [Table 2](#) for the list of peripherals available on each part number.

The STM32F469xx devices operate in the –40 to +105 °C temperature range from a 1.7 to 3.6 V power supply. A dedicated supply input for USB (OTG_FS and OTG_HS) only in full speed mode, is available on all packages.

The supply voltage can drop to 1.7 V (refer to [Section 2.19.2](#)). A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F469xx devices are offered in eight packages, ranging from 100 to 216 pins. The set of included peripherals changes with the device chosen, according to [Table 2](#).

1.1.2 LQFP208 package

Figure 2. Incompatible board design for LQFP208 package

STM32F469xx/479xx LQFP208	138	☐	PC6	STM32F42x/STM32F43x LQFP208	138	☐	PC6
	137	☒	VDDUSB		137	☐	VDD
	136	☐	VSS		136	☐	VSS
	135	☐	PG8		135	☐	PG8
	134	☐	PG7		134	☐	PG7
	133	☐	PG6		133	☐	PG6
	132	☐	PG5		132	☐	PG5
	131	☐	PG4		131	☐	PG4
	130	☐	PG3		130	☐	PG3
	129	☐	PG2		129	☐	PG2
	128	☒	VSSDSI		128	☐	PK2
	127	☒	DSIHOST_D1N		127	☐	PK1
	126	☒	DSIHOST_D1P		126	☐	PK0
	125	☒	VDD12DSI		125	☐	VSS
	124	☒	DSIHOST_CKN		124	☐	VDD
	123	☒	DSIHOST_CKP		123	☐	PJ11
	122	☒	VSSDSI		122	☐	PJ10
	121	☒	DSIHOST_D0N		121	☐	PJ9
	120	☒	DSIHOST_D0P		120	☐	PJ8
	119	☒	VCAPDSI		119	☐	PJ7
	118	☒	VDDDSI		118	☐	PJ6
	117	☐	PD15		117	☐	PD15
	116	☐	PD14		116	☐	PD14

MS38295V1

1. Pins from 118 to 128 and pin 137 are not compatible

The major features are:

- Combined Rx and Tx FIFO size of 4 KB with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 8 bidirectional endpoints
- 16 host channels with periodic OUT support
- Software configurable to OTG1.3 and OTG2.0 modes of operation
- USB 2.0 LPM (Link Power Management) support
- Internal FS OTG PHY support
- External HS or HS OTG operation supporting ULPI in SDR mode. The OTG PHY is connected to the microcontroller ULPI port through 12 signals. It can be clocked using the 60 MHz output.
- Internal USB DMA
- HNP/SNP/IP inside (no need for any external resistor)
- for OTG/Host modes, a power switch is needed in case bus-powered devices are connected

2.37 Digital camera interface (DCMI)

The devices embed a camera interface that can connect with camera modules and CMOS sensors through an 8-bit to 14-bit parallel interface, to receive video data. The camera interface can sustain a data transfer rate up to 54 Mbyte/s at 54 MHz. It features:

- Programmable polarity for the input pixel clock and synchronization signals
- Parallel data communication can be 8-, 10-, 12- or 14-bit
- Supports 8-bit progressive video monochrome or raw bayer format, YCbCr 4:2:2 progressive video, RGB 565 progressive video or compressed data (like JPEG)
- Supports continuous mode or snapshot (a single frame) mode
- Capability to automatically crop the image black & white.

2.38 Random number generator (RNG)

All devices embed an RNG that delivers 32-bit random numbers generated by an integrated analog circuit.

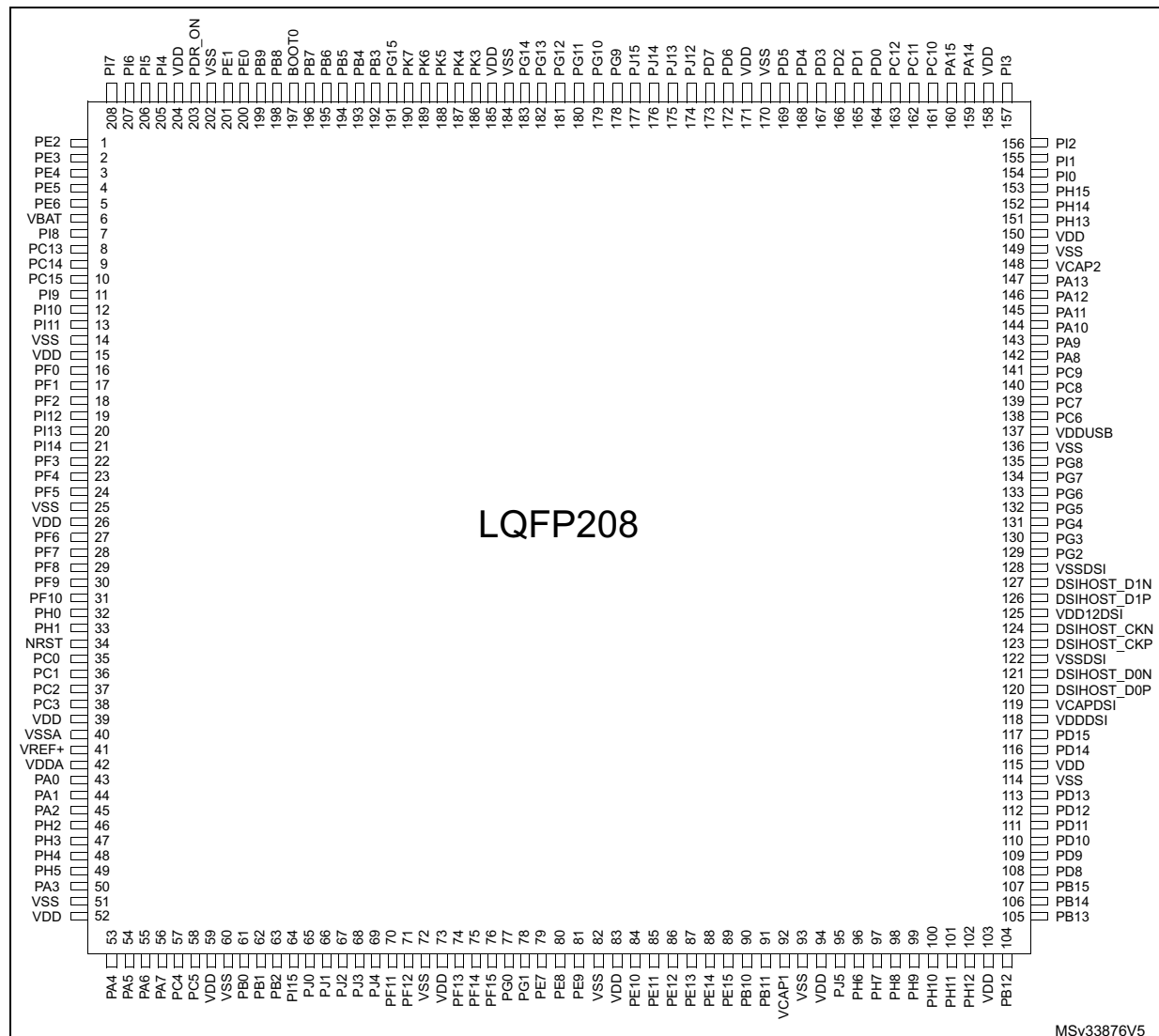
2.39 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

The I/O configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

Fast I/O handling allowing maximum I/O toggling up to 90 MHz.

Figure 19. STM32F46x LQFP208 pinout



1. The above figure shows the package top view.

Table 10. STM32F469xx pin and ball definitions

Pin number								Pin name (function after reset) ⁽¹⁾	Pin types	I/O structures	Notes	Alternate functions	Additional functions
LQFP100	LQFP144	UFBGA169	WLCSP168	UFBGA176	LQFP176	LQFP208	TFBGA216						
1	144	B2	F9	A2	1	1	A3	PE2	I/O	FT	-	TRACECLK, SPI4_SCK, SAI1_MCLK_A, QUADSPI_BK1_IO2, ETH_MII_TXD3, FMC_A23, EVENTOUT	-
NC (2)	1	C1	E10	A1	2	2	A2	PE3	I/O	FT	-	TRACED0, SAI1_SD_B, FMC_A19, EVENTOUT	-
NC (2)	2	C2	C11	B1	3	3	A1	PE4	I/O	FT	-	TRACED1, SPI4_NSS, SAI1_FS_A, FMC_A20, DCMI_D4, LCD_B0, EVENTOUT	-
NC (2)	3	D1	B12	B2	4	4	B1	PE5	I/O	FT	-	TRACED2, TIM9_CH1, SPI4_MISO, SAI1_SCK_A, FMC_A21, DCMI_D6, LCD_G0, EVENTOUT	-
NC (2)	4	D2	D11	B3	5	5	B2	PE6	I/O	FT	-	TRACED3, TIM9_CH2, SPI4_MOSI, SAI1_SD_A, FMC_A22, DCMI_D7, LCD_G1, EVENTOUT	-
2	-	-	-	-	-	-	G6	VSS	S	-	-	-	-
-	-	-	-	-	-	-	F5	VDD	S	-	-	-	-
3	5	E5	C12	C1	6	6	C1	VBAT	S	-	-	-	-
-	-	-	-	D2	7	7	C2	PI8	I/O	FT	(3) (4)	EVENTOUT	RTC_TAMP1/ RTC_TAMP2/ RTC_TS
4	6	G4	D12	D1	8	8	D1	PC13	I/O	FT	(3) (4)	EVENTOUT	RTC_TAMP1/ RTC_TS/ RTC_OUT
5	7	E1	E11	E1	9	9	E1	PC14-OSC32_IN (PC14)	I/O	FT	(3) (4)	EVENTOUT	OSC32_IN
6	8	F1	E12	F1	10	10	F1	PC15- OSC32_OUT (PC15)	I/O	FT	(3) (4)	EVENTOUT	OSC32_OUT
-	-	-	-	-	-	-	G5	VDD	S	-	-	-	-
-	-	E2	G9	D3	11	11	E4	PI9	I/O	FT	-	CAN1_RX, FMC_D30, LCD_VSYNC, EVENTOUT	-
-	-	E4	F10	E3	12	12	D5	PI10	I/O	FT	-	ETH_MII_RX_ER, FMC_D31, LCD_HSYNC, EVENTOUT	-
-	-	F2	F11	E4	13	13	F3	PI11	I/O	FT	-	LCD_G6, OTG_HS_ULPI_DIR, EVENTOUT	-
-	-	F5	F12	F2	14	14	F2	VSS	S	-	-	-	-
-	-	F4	G11	F3	15	15	F4	VDD	S	-	-	-	-

Table 10. STM32F469xx pin and ball definitions (continued)

Pin number								Pin name (function after reset) ⁽¹⁾	Pin types	I/O structures	Notes	Alternate functions	Additional functions
LQFP100	LQFP144	UFBGA169	WLCSP168	UFBGA176	LQFP176	LQFP208	TFBGA216						
-	9	F3	G10	E2	16	16	D2	PF0	I/O	FT		I2C2_SDA, FMC_A0, EVENTOUT	-
-	10	G3	H10	H3	17	17	E2	PF1	I/O	FT		I2C2_SCL, FMC_A1, EVENTOUT	-
-	11	G5	G12	H2	18	18	G2	PF2	I/O	FT		I2C2_SMBA, FMC_A2, EVENTOUT	-
-	-	-	-	-	-	19	E3	PI12	I/O	FT		LCD_HSYNC, EVENTOUT	-
-	-	-	-	-	-	20	G3	PI13	I/O	FT		LCD_VSYNC, EVENTOUT	-
-	-	-	-	-	-	21	H3	PI14	I/O	FT		LCD_CLK, EVENTOUT	-
-	12	H4	H11	J2	19	22	H2	PF3	I/O	FT	(5)	FMC_A3, EVENTOUT	ADC3_IN9
-	13	L4	J10	J3	20	23	J2	PF4	I/O	FT	(5)	FMC_A4, EVENTOUT	ADC3_IN14
-	14	H3	H12	K3	21	24	K3	PF5	I/O	FT	(5)	FMC_A5, EVENTOUT	ADC3_IN15
7	15	G7	J11	G2	22	25	H6	VSS	S	-	-	-	-
8	16	G8	J12	G3	23	26	H5	VDD	S	-	-	-	-
-	-	-	-	K2	24	27	K2	PF6	I/O	FT	(5)	TIM10_CH1, SPI5_NSS, SAI1_SD_B, UART7_Rx, QUADSPI_BK1_IO3, EVENTOUT	ADC3_IN4
-	-	-	-	K1	25	28	K1	PF7	I/O	FT	(5)	TIM11_CH1, SPI5_SCK, SAI1_MCLK_B, UART7_Tx, QUADSPI_BK1_IO2, EVENTOUT	ADC3_IN5
-	-	-	-	L3	26	29	L3	PF8	I/O	FT	(5)	SPI5_MISO, SAI1_SCK_B, TIM13_CH1, QUADSPI_BK1_IO0, EVENTOUT	ADC3_IN6
-	-	-	-	L2	27	30	L2	PF9	I/O	FT	(5)	SPI5_MOSI, SAI1_FS_B, TIM14_CH1, QUADSPI_BK1_IO1, EVENTOUT	ADC3_IN7
-	17	H1	K10	L1	28	31	L1	PF10	I/O	FT	(5)	QUADSPI_CLK, DCMI_D11, LCD_DE, EVENTOUT	ADC3_IN8
9	18	G2	K11	G1	29	32	G1	PH0-OSC_IN (PH0)	I/O	FT	-	EVENTOUT	OSC_IN
10	19	G1	K12	H1	30	33	H1	PH1-OSC_OUT (PH1)	I/O	FT	-	EVENTOUT	OSC_OUT
11	20	H2	H9	J1	31	34	J1	NRST	I/O	RST	-		
12	21	M1	J9	M2	32	35	M2	PC0	I/O	FT	(5)	OTG_HS_ULPI_STP, FMC_SDNWE, LCD_R5, EVENTOUT	ADC123_ IN10

Table 10. STM32F469xx pin and ball definitions (continued)

Pin number								Pin name (function after reset) ⁽¹⁾	Pin types	I/O structures	Notes	Alternate functions	Additional functions
LQFP100	LQFP144	UFBGA169	WL CSP168	UFBGA176	LQFP176	LQFP208	TFBGA216						
-	96	D13	G6	H14	116	135	H14	PG8	I/O	FT	-	SPI6_NSS, USART6_RTS, ETH_PPS_OUT, FMC_SDCLK, LCD_G7, EVENTOUT	-
-	-	G9	F2	G12	117	136	G10	VSS	S	-	-	-	-
65	97	G11	F1	H13	118	137	G11	VDDUSB	S	-	-	-	-
66	98	F9	F3	H15	119	138	H15	PC6	I/O	FT	-	TIM3_CH1, TIM8_CH1, I2S2_MCK, USART6_TX, SDIO_D6, DCMI_D0, LCD_HSYNC, EVENTOUT	-
67	99	F10	G7	G15	120	139	G15	PC7	I/O	FT	-	TIM3_CH2, TIM8_CH2, I2S3_MCK, USART6_RX, SDIO_D7, DCMI_D1, LCD_G6, EVENTOUT	-
68	100	E10	F4	G14	121	140	G14	PC8	I/O	FT	-	TRACED1, TIM3_CH3, TIM8_CH3, USART6_CK, SDIO_D0, DCMI_D2, EVENTOUT	-
69	101	G10	F5	F14	122	141	F14	PC9	I/O	FT	-	MCO2, TIM3_CH4, TIM8_CH4, I2C3_SDA, I2S_CKIN, QUADSPI_BK1_IO0, SDIO_D1, DCMI_D3, EVENTOUT	-
70	102	D8	E1	F15	123	142	F15	PA8	I/O	FT	-	MCO1, TIM1_CH1, I2C3_SCL, USART1_CK, OTG_FS_SOF, LCD_R6, EVENTOUT	-
71	103	E8	E2	E15	124	143	E15	PA9	I/O	FT	-	TIM1_CH2, I2C3_SMBA, SPI2_SCK/I2S2_CK, USART1_TX, DCMI_D0, EVENTOUT	OTG_FS_VBUS
72	104	E9	E3	D15	125	144	D15	PA10	I/O	FT	-	TIM1_CH3, USART1_RX, OTG_FS_ID, DCMI_D1, EVENTOUT	-
73	105	A13	F7	C15	126	145	C15	PA11	I/O	FT	-	TIM1_CH4, USART1_CTS, CAN1_RX, OTG_FS_DM, LCD_R4, EVENTOUT	-
74	106	A12	F6	B15	127	146	B15	PA12	I/O	FT	-	TIM1_ETR, USART1_RTS, CAN1_TX, OTG_FS_DP, LCD_R5, EVENTOUT	-
75	107	A11	D1	A15	128	147	A15	PA13(JTMS-SWDIO)	I/O	FT	-	JTMS-SWDIO, EVENTOUT	-
76	108	D12	D2	F13	129	148	E11	VCAP2	S	-	-	-	-
-	109	D11	C1	F12	130	149	F10	VSS	S	-	-	-	-

Table 11. FMC pin definition

Pin name	NOR/PSRAM/SRAM	NOR/PSRAM Mux	NAND16	SDRAM
PF0	A0	-	-	A0
PF1	A1	-	-	A1
PF2	A2	-	-	A2
PF3	A3	-	-	A3
PF4	A4	-	-	A4
PF5	A5	-	-	A5
PF12	A6	-	-	A6
PF13	A7	-	-	A7
PF14	A8	-	-	A8
PF15	A9	-	-	A9
PG0	A10	-	-	A10
PG1	A11	-	-	A11
PG2	A12	-	-	A12
PG3	A13	-	-	
PG4	A14	-	-	BA0
PG5	A15	-	-	BA1
PD11	A16	A16	CLE	-
PD12	A17	A17	ALE	-
PD13	A18	A18	-	-
PE3	A19	A19	-	-
PE4	A20	A20	-	-
PE5	A21	A21	-	-
PE6	A22	A22	-	-
PE2	A23	A23	-	-
PG13	A24	A24	-	-
PG14	A25	A25	-	-
PD14	D0	DA0	D0	D0
PD15	D1	DA1	D1	D1
PD0	D2	DA2	D2	D2
PD1	D3	DA3	D3	D3
PE7	D4	DA4	D4	D4
PE8	D5	DA5	D5	D5
PE9	D6	DA6	D6	D6
PE10	D7	DA7	D7	D7
PE11	D8	DA8	D8	D8



Table 12. Alternate function (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7	AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		SYS	TIM1/2	TIM3/4/ 5	TIM8/9/ 10/11	I2C1/2/3	SPI1/2/3 I4/5/6	SPI2/3/ SAI1	SPI2/3/ USART 1/2/3	USAR T6/ UART 4/5/7/ 8	CAN1/2/ TIM12/ 13/14/ QUAD SPI/LCD	QUAD SPI/OT G2_HS /OTG1 _FS	ETH	FMC/ SDIO/ OTG2_ FS	DCMI/ DSI HOST	LCD	SYS
Port D	PD0	-	-	-	-	-	-	-	-	-	CAN1_RX	-	-	FMC_D2	-	-	EVENT OUT
	PD1	-	-	-	-	-	-	-	-	-	CAN1_TX	-	-	FMC_D3	-	-	EVENT OUT
	PD2	TRACE D2	-	TIM3_ETR	-	-	-	-	-	UART5_ RX	-	-	-	SDIO_CMD	DCMI_D11	-	EVENT OUT
	PD3	-	-	-	-	-	SPI2_SCK/I 2S2_CK	-	USART2_ CTS	-	-	-	-	FMC_CLK	DCMI_D5	LCD_G7	EVENT OUT
	PD4	-	-	-	-	-	-	-	USART2_ RTS	-	-	-	-	FMC_NOE	-	-	EVENT OUT
	PD5	-	-	-	-	-	-	-	USART2_T X	-	-	-	-	FMC_NWE	-	-	EVENT OUT
	PD6	-	-	-	-	-	SPI3_MOSI /I2S3_SD	SAI1_SD_ A	USART2_ RX	-	-	-	-	FMC_NWAI T	DCMI_D10	LCD_B2	EVENT OUT
	PD7	-	-	-	-	-	-	-	USART2_ CK	-	-	-	-	FMC_NE1	-	-	EVENT OUT
	PD8	-	-	-	-	-	-	-	USART3_T X	-	-	-	-	FMC_D13	-	-	EVENT OUT
	PD9	-	-	-	-	-	-	-	USART3_ RX	-	-	-	-	FMC_D14	-	-	EVENT OUT
	PD10	-	-	-	-	-	-	-	USART3_ CK	-	-	-	-	FMC_D15	-	LCD_B3	EVENT OUT
	PD11	-	-	-	-	-	-	-	USART3_ CTS	-	QUADSPI_ BK1_IO0	-	-	FMC_A16/F MC_CLE	-	-	EVENT OUT
	PD12	-	-	TIM4_CH1	-	-	-	-	USART3_ RTS	-	QUADSPI_ BK1_IO1	-	-	FMC_A17/F MC_ALE	-	-	EVENT OUT
	PD13	-	-	TIM4_CH2	-	-	-	-	-	-	QUADSPI_ BK1_IO3	-	-	FMC_A18	-	-	EVENT OUT
	PD14	-	-	TIM4_CH3	-	-	-	-	-	-	-	-	-	FMC_D0	-	-	EVENT OUT
	PD15	-	-	TIM4_CH4	-	-	-	-	-	-	-	-	-	FMC_D1	-	-	EVENT OUT

Table 15. Current characteristics

Symbol	Ratings	Max.	Unit
ΣI_{VDD}	Total current into sum of all V_{DD_x} power lines (source) ⁽¹⁾	290	mA
ΣI_{VSS}	Total current out of sum of all V_{SS_x} ground lines (sink) ⁽¹⁾	– 290	
ΣI_{VDDUSB}	Total current into V_{DDUSB} power line (source)	25	
I_{VDD}	Maximum current into each V_{DD_x} power line (source) ⁽¹⁾	100	
I_{VSS}	Maximum current out of each V_{SS_x} ground line (sink) ⁽¹⁾	– 100	
I_{IO}	Output current sunk by any I/O and control pin	25	
	Output current sourced by any I/Os and control pin	– 25	
ΣI_{IO}	Total output current sunk by sum of all I/O and control pins ⁽²⁾	120	
	Total output current sunk by sum of all USB I/Os	25	
	Total output current sourced by sum of all I/Os and control pins ⁽²⁾	– 120	
$I_{INJ(PIN)}^{(3)}$	Injected current on FT pins ⁽⁴⁾	– 5/+0	
	Injected current on NRST and BOOT0 pins ⁽⁴⁾		
	Injected current on TTa pins ⁽⁵⁾	±5	
$\Sigma I_{INJ(PIN)}^{(5)}$	Total injected current (sum of all I/O and control pins) ⁽⁶⁾	±25	

1. All main power (V_{DD} , V_{DDA}) and ground (V_{SS} , V_{SSA}) pins must always be connected to the external power supply, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count LQFP packages.
3. Negative injection disturbs the analog performance of the device. See note in [Section 5.3.24](#).
4. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
5. A positive injection is induced by $V_{IN} > V_{DDA}$ while a negative injection is induced by $V_{IN} < V_{SS}$. $I_{INJ(PIN)}$ must never be exceeded. Refer to [Table 14](#) for the values of the maximum allowed input voltage.
6. When several inputs are submitted to a current injection, the maximum $\Sigma I_{INJ(PIN)}$ is the absolute sum of the positive and negative injected currents (instantaneous values).

Table 16. Thermal characteristics

Symbol	Ratings	Value	Unit
T_{STG}	Storage temperature range	– 65 to +150	°C
T_J	Maximum junction temperature	125	°C

Table 25. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled), regulator ON

Symbol	Parameter	Conditions	f _{HCLK} (MHz)	Typ	Max ⁽¹⁾			Unit
					T _A = 25 °C	T _A = 85 °C	T _A = 105 °C	
I _{DD}	Supply current in RUN mode	All Peripherals enabled ⁽²⁾⁽³⁾	168	97	102	128	154	mA
			150	87	92	118	143	
			144	80	84	108	131	
			120	65	68	88	108	
			90	51	54	73	93	
			60	37	41	59	79	
			30	21	23	42	62	
			25	18	20	39	59	
		All Peripherals disabled	168	49	55	79	105	
			150	44	49	44	100	
			144	40	45	68	92	
			120	36	39	58	78	
			90	29	32	51	71	
			60	22	25	44	64	
			30	13	15	34	54	
			25	11	13	32	52	

1. Guaranteed based on test during characterization.
2. When analog peripheral blocks such as ADCs, DACs, HSE, LSE, HSI, or LSI are ON, an additional power consumption should be considered.
3. When the ADC is ON (ADON bit set in the ADC_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

Table 36. Low-speed external user clock characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$C_{in(LSE)}$	OSC32_IN input capacitance ⁽¹⁾	-	-	5	-	pF
$DuCy_{(LSE)}$	Duty cycle	-	30	-	70	%
I_L	OSC32_IN Input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	± 1	μA

1. Guaranteed by design.

Figure 29. High-speed external clock source AC timing diagram

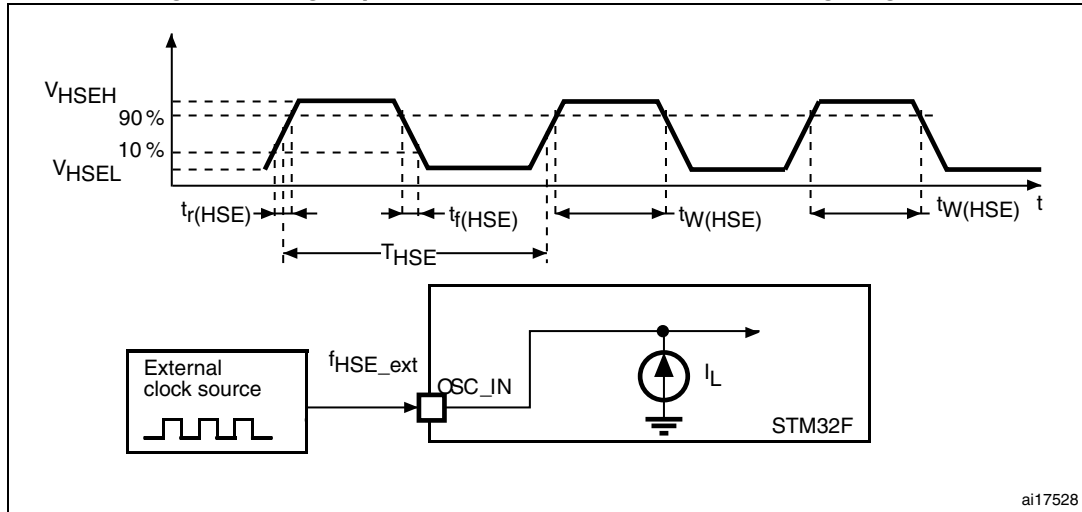
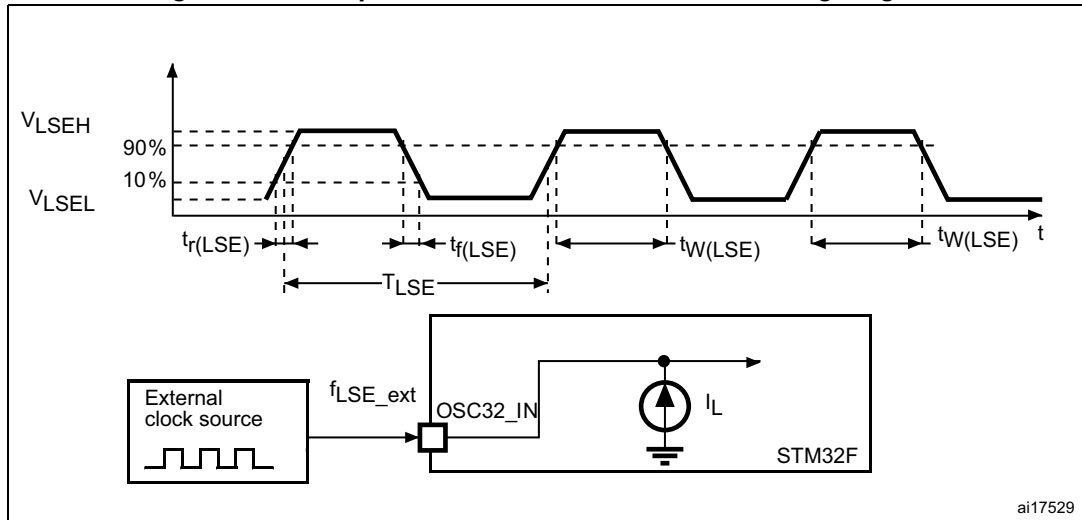


Figure 30. Low-speed external clock source AC timing diagram



High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 26 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 37](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization

Table 58. I/O static characteristics (continued)

Symbol	Parameter		Conditions	Min	Typ	Max	Unit
V _{HYS}	FT, TTA and NRST I/O input hysteresis		1.7 V ≤ V _{DD} ≤ 3.6 V	10%V _{DD} ⁽³⁾	-	-	V
	BOOT0 I/O input hysteresis		1.75 V ≤ V _{DD} ≤ 3.6 V, −40 °C ≤ T _A ≤ 105 °C	0.1	-	-	
			1.7 V ≤ V _{DD} ≤ 3.6 V, 0 °C ≤ T _A ≤ 105 °C				
I _{lkg}	I/O input leakage current ⁽⁴⁾		V _{SS} ≤ V _{IN} ≤ V _{DD}	-	-	±1	μA
	I/O FT input leakage current ⁽⁵⁾		V _{IN} = 5 V	-	-	3	
R _{PU}	Weak pull-up equivalent resistor ⁽⁶⁾	All pins except for PA10/PB12 (OTG_FS_ID, OTG_HS_ID)	V _{IN} = V _{SS}	30	40	50	kΩ
		PA10/PB12 (OTG_FS_ID, OTG_HS_ID)		7	10	14	
R _{PD}	Weak pull-down equivalent resistor ⁽⁷⁾	All pins except for PA10/PB12 (OTG_FS_ID, OTG_HS_ID)	V _{IN} = V _{DD}	30	40	50	
		PA10/PB12 (OTG_FS_ID, OTG_HS_ID)		7	10	14	
C _{IO} ⁽⁸⁾	I/O pin capacitance		-	-	5	-	pF

1. Guaranteed by design.
2. Tested in production.
3. With a minimum of 200 mV.
4. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins, Refer to [Table 57](#)
5. To sustain a voltage higher than VDD +0.3 V, the internal pull-up/pull-down resistors must be disabled. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins. Refer to [Table 57](#)
6. Pull-up resistors are designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimum (~10% order).
7. Pull-down resistors are designed with a true resistance in series with a switchable NMOS. This NMOS contribution to the series resistance is minimum (~10% order).
8. Hysteresis voltage between Schmitt trigger switching levels. Based on test during characterization.

Table 71. USB HS clock timing parameters⁽¹⁾

Symbol	Parameter		Min	Typ	Max	Unit
-	f_{HCLK} value to guarantee proper operation of USB HS interface		30	-	-	MHz
F_{START_8BIT}	Frequency (first transition)	8-bit $\pm 10\%$	54	60	66	
F_{STEADY}	Frequency (steady state) ± 500 ppm		59.97	60	60.03	
D_{START_8BIT}	Duty cycle (first transition)	8-bit $\pm 10\%$	40	50	60	%
D_{STEADY}	Duty cycle (steady state) ± 500 ppm		49.975	50	50.025	
t_{STEADY}	Time to reach the steady state frequency and duty cycle after the first transition		-	-	1.4	ms
t_{START_DEV}	Clock startup time after the de-assertion of SuspendM	Peripheral	-	-	5.6	ms
t_{START_HOST}		Host	-	-	-	
t_{PREP}	PHY preparation time after the first transition of the input clock		-	-	-	μs

1. Guaranteed by design.

Figure 50. ULPI timing diagram

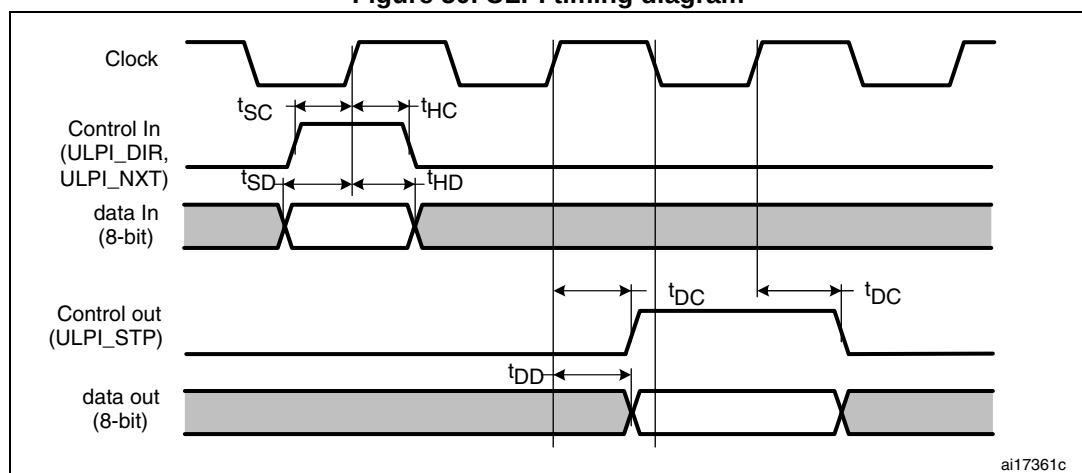


Table 97. Synchronous multiplexed PSRAM write timings⁽¹⁾

Symbol	Parameter	Min	Max	Unit
$t_{w(CLK)}$	FMC_CLK period, V_{DD} range= 2.7 to 3.6 V	$2T_{HCLK} - 1$	-	ns
$t_{d(CLKL-NExL)}$	FMC_CLK low to FMC_NEx low ($x=0\dots2$)	-	1.5	
$t_{d(CLKH-NExH)}$	FMC_CLK high to FMC_NEx high ($x=0\dots2$)	T_{HCLK}	-	
$t_{d(CLKL-NADV_L)}$	FMC_CLK low to FMC_NADV low	-	0	
$t_{d(CLKL-NADV_H)}$	FMC_CLK low to FMC_NADV high	0	-	
$t_{d(CLKL-AV)}$	FMC_CLK low to FMC_Ax valid ($x=16\dots25$)	-	0	
$t_{d(CLKH-AIV)}$	FMC_CLK high to FMC_Ax invalid ($x=16\dots25$)	T_{HCLK}	-	
$t_{d(CLKL-NWEL)}$	FMC_CLK low to FMC_NWE low	-	0	
$t_{d(CLKH-NWEH)}$	FMC_CLK high to FMC_NWE high	$T_{HCLK}-0.5$	-	
$t_{d(CLKL-ADV)}$	FMC_CLK low to FMC_AD[15:0] valid	-	3	
$t_{d(CLKL-ADIV)}$	FMC_CLK low to FMC_AD[15:0] invalid	0	-	
$t_{d(CLKL-DATA)}$	FMC_A/D[15:0] valid data after FMC_CLK low	-	3	
$t_{d(CLKL-NBL_L)}$	FMC_CLK low to FMC_NBL low	0	-	
$t_{d(CLKH-NBL_H)}$	FMC_CLK high to FMC_NBL high	$T_{HCLK}-0.5$	-	
$t_{su(NWAIT-CLKH)}$	FMC_NWAIT valid before FMC_CLK high	4	-	
$t_h(CLKH-NWAIT)$	FMC_NWAIT valid after FMC_CLK high	0	-	

1. Based on test during characterization.

Figure 70. NAND controller waveforms for common memory write access

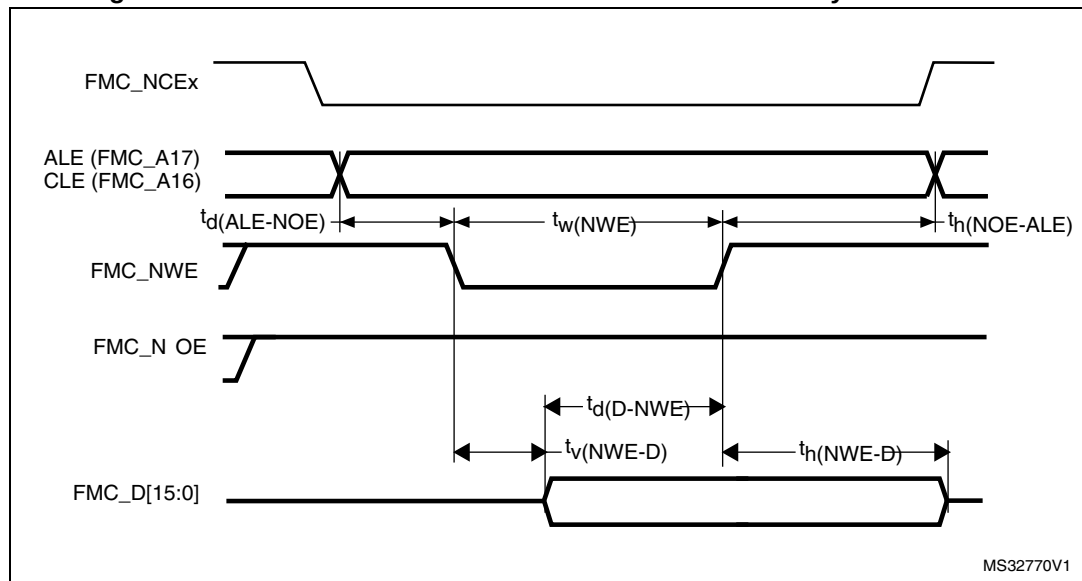


Table 100. Switching characteristics for NAND Flash read cycles

Symbol	Parameter	Min	Max	Unit
$t_{w(NOE)}$	FMC_NOE low width	$4T_{HCLK} - 0.5$	$4T_{HCLK} + 0.5$	ns
$t_{su(D-NOE)}$	FMC_D[15-0] valid data before FMC_NOE high	9	-	
$t_h(NOE-D)$	FMC_D[15-0] valid data after FMC_NOE high	0	-	
$t_d(ALE-NOE)$	FMC_ALE valid before FMC_NOE low	-	$3T_{HCLK} - 0.5$	
$t_h(NOE-ALE)$	FMC_NWE high to FMC_ALE invalid	$3T_{HCLK} - 2$	-	

Table 101. Switching characteristics for NAND Flash write cycles

Symbol	Parameter	Min	Max	Unit
$t_{w(NWE)}$	FMC_NWE low width	$4T_{HCLK}$	$4T_{HCLK} + 1$	ns
$t_{v(NWE-D)}$	FMC_NWE low to FMC_D[15-0] valid	0	-	
$t_h(NWE-D)$	FMC_NWE high to FMC_D[15-0] invalid	$3T_{HCLK} - 1$	-	
$t_d(D-NWE)$	FMC_D[15-0] valid before FMC_NWE high	$5T_{HCLK} - 3$	-	
$t_d(ALE-NWE)$	FMC_ALE valid before FMC_NWE low	-	$3T_{HCLK} - 0.5$	
$t_h(NWE-ALE)$	FMC_NWE high to FMC_ALE invalid	$3T_{HCLK} - 1$	-	

SDRAM waveforms and timings

- $C_L = 30$ pF on data and address lines.
- $C_L = 10$ pF on FMC_SDCLK unless otherwise specified.

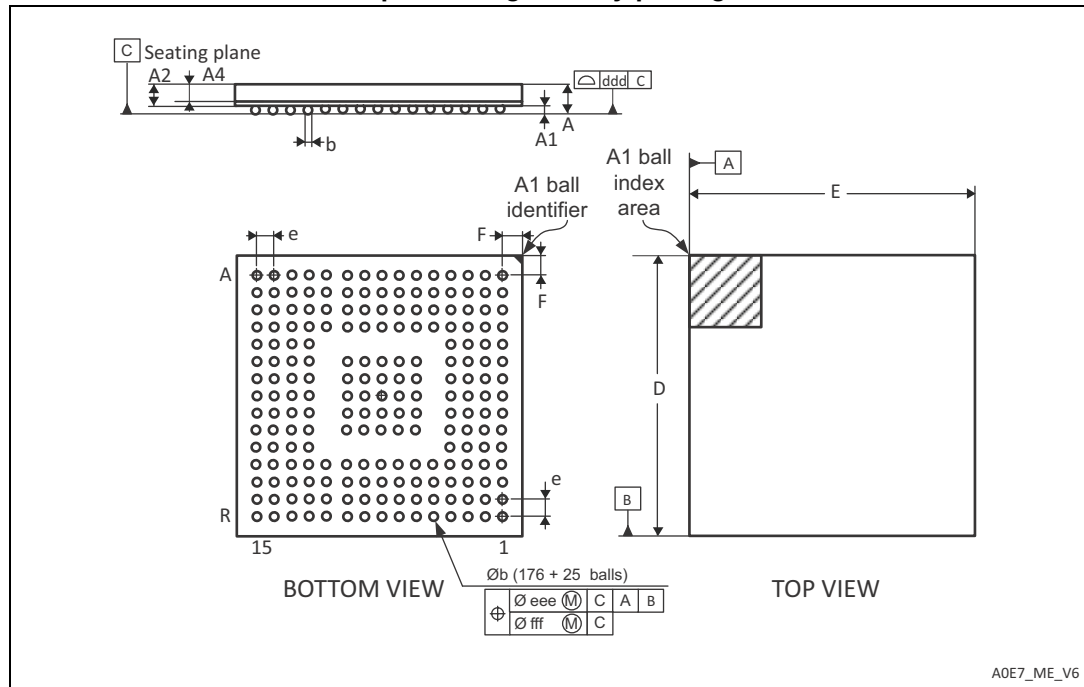
**Table 117. LQFP176, 24 x 24 mm, 176-pin low-profile quad flat package
mechanical data (continued)**

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
e	-	0.500	-	-	0.0197	-
HD	25.900	-	26.100	1.0200	-	1.0276
HE	25.900	-	26.100	1.0200	-	1.0276
L	0.450	-	0.750	0.0177	-	0.0295
L1	-	1.000	-	-	0.0394	-
ZD	-	1.250	-	-	0.0492	-
ZE	-	1.250	-	-	0.0492	-
ccc	-	-	0.080	-	-	0.0031
k	0 °	-	7 °	0 °	-	7 °

1. Values in inches are converted from mm and rounded to 4 decimal digits.

6.6 UFBGA176+25 package information

Figure 92. UFBGA176+25 - 201-ball, 10 x 10 mm, 0.65 mm pitch, ultra fine pitch ball grid array package outline



1. Drawing is not to scale.

Table 118. UFBGA176+25, - 201-ball, 10 x 10 mm, 0.65 mm pitch, ultra fine pitch ball grid array package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.460	0.530	0.600	0.0181	0.0209	0.0236
A1	0.050	0.080	0.110	0.0020	0.0031	0.0043
A2	0.400	0.450	0.500	0.0157	0.0177	0.0197
A4	0.270	0.320	0.370	0.0106	0.0126	0.0146
b	0.230	0.280	0.330	0.0091	0.0110	0.0130
D	9.950	10.000	10.050	0.3917	0.3937	0.3957
E	9.950	10.000	10.050	0.3917	0.3937	0.3957
e	-	0.650	-	-	0.0256	-
F	0.400	0.450	0.500	0.0157	0.0177	0.0197
ddd	-	-	0.080	-	-	0.0031
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.